

INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)

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| ATTY DOCKET NO. YOR92001056SUS2 | SERIAL NO. 10/787,487 <u>Not Yet Assigned</u> |
| Clevenger et al. | |
| FILING 09/26/04 <u>Concurrently Herewith</u> | GROUP 2822 <u>Unknown</u> |

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| EXAMINER | DATE CONSIDERED |
| T. M. Thomas | 06-24-05 |

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



Substitute for form 1449A/PTO

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet

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Complete If Known

| | |
|------------------------|-------------------------------|
| Application Number | 10/787,487 |
| Filing Date | 02/26/04 |
| First Named Inventor | Clevenger et al. |
| Group Art Unit | 2522 3822 |
| Examiner Name | -Net Yet Assigned T.M. Thomas |
| Attorney Docket Number | YOR920010565US2 |

Already →
considered.
See 1449
filed 05/26/04.

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| | | Foreign Patent Number | | Name of Patentee or Applicant/Inventor of Cited Document | Date of Publication of Cited Document MM-DD-YYYY | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear | T ⁶ |
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| Examiner Initials* | Cite No. ¹ | Office ³ | Number | Kind Code ⁵ (if known) | | | |
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

| EXAMINER LITERATURE DOCUMENTS | | |
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| Examiner Initials* | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published |
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| Examiner Signature | T. M. Thomas | Date Considered | 06-24-05 |
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¹ Unique citation designation number. ² See attached *Kinds of U.S. Patent Documents*. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.